

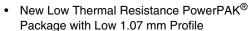


# N-Channel 12-V (D-S) MOSFET

PRODUCT SUMMARY					
V <sub>DS</sub> (V)	$R_{DS(on)}$ ( $\Omega$ )	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)		
12	0.0026 at V <sub>GS</sub> = 4.5 V	29	54		
	0.0037 at V <sub>GS</sub> = 2.5 V	23	54		

#### **FEATURES**

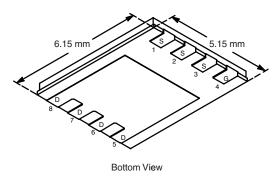
- · Halogen-free available
- TrenchFET<sup>®</sup> Power MOSFET



100 % R<sub>g</sub> Tested



#### PowerPAK SO-8

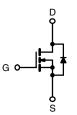


Ordering Information: Si7858ADP-T1-E3 (Lead (Pb)-free)

Si7858ADP-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### **APPLICATIONS**

 Low Output Voltage, High Current Synchronous Rectifiers



N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		$V_{DS}$	12		V	
Gate-Source Voltage		$V_{GS}$	± 8			
Continuous Drain Current (T <sub>.I</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	29	20	A	
Continuous Drain Current (1) = 150 C)	T <sub>A</sub> = 70 °C		23	16		
Pulsed Drain Current (10 μs Pulse Width)		I <sub>DM</sub>	60		A	
Continuous Source Current (Diode Conduction) <sup>a</sup>		l <sub>S</sub>	4.5	1.6	1	
Maximum Dawar Dissinationa	T <sub>A</sub> = 25 °C	- P <sub>D</sub>	5.4	1.9	W	
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		3.4	1.2		
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	- 55 to 150		°C	
Soldering Recommendations (Peak Temperature) <sup>b,c</sup>			260		O	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maniana Indiana da Anabianda	t ≤ 10 s	R <sub>thJA</sub>	18	23	°C/W	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		50	65		
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	1.0	1.5		

#### Notes:

- a. Surface Mounted on 1" x 1" FR4 board.
- b. See Solder Profile ( <a href="http://www.vishay.com/ppg?73257">http://www.vishay.com/ppg?73257</a>). The PowerPAK SO-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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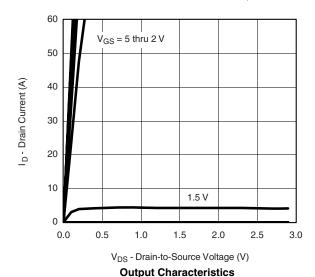
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			L		<u> </u>		
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.6	0.95	1.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zana Cata Valtana Busin Comment	1	V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 0 V		1			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 12 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			10	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	30			Α	
Drain-Source On-State Resistance <sup>a</sup>	В	$V_{GS} = 4.5 \text{ V}, I_D = 29 \text{ A}$		0.0020	0.0026	Ω	
	R <sub>DS(on)</sub>	$V_{GS} = 2.5 \text{ V}, I_D = 23 \text{ A}$		0.0029	0.0037		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 6 \text{ V}, I_{D} = 29 \text{ A}$		130		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	I <sub>S</sub> = 2.9 A, V <sub>GS</sub> = 0 V		0.75	1.1	V	
Dynamic <sup>b</sup>							
Input Capacitance	C <sub>iss</sub>			5700			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 6 \text{ V}, V_{SS} = 0 \text{ V}, f = 1 \text{ MHz}$		2680		pF	
Reverse Transfer Capacitance	C <sub>rss</sub>			1280			
Total Gate Charge	$Q_g$	V <sub>DS</sub> = 6 V, V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 29 A		54	80		
Gate-Source Charge	Q <sub>gs</sub>			10		nC	
Gate-Drain Charge	$Q_{gd}$			16			
Gate Resistance	$R_g$		0.5	1.2	2.0	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			40	60		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 6 V, $R_L$ = 6 $\Omega$		40	60	ns	
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D\cong$ 1 A, $V_{GEN}$ = 4.5 V, $R_G$ = 6 $\Omega$		140	210		
Fall Time	t <sub>f</sub>			70	100		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.9 A, di/dt = 100 A/μs		50	80		

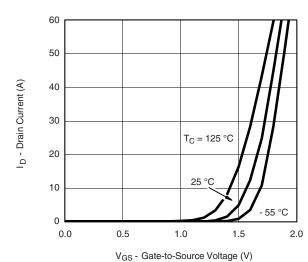
## Notes:

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

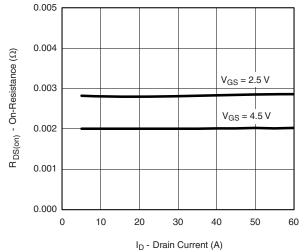




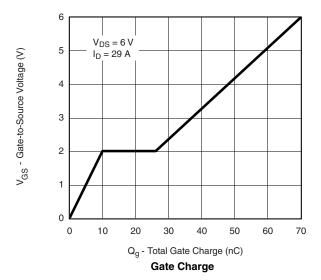
**Transfer Characteristics** 

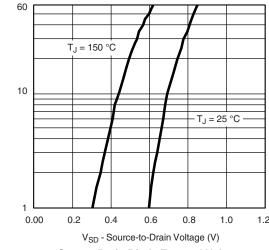


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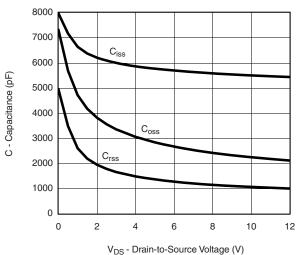


#### On-Resistance vs. Drain Current

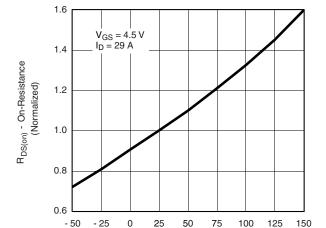




Source-Drain Diode Forward Voltage

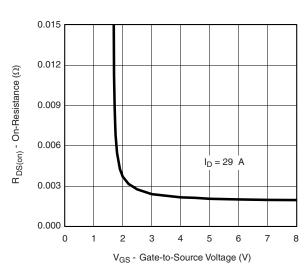


Capacitance



T<sub>J</sub> - Junction Temperature (°C)

On-Resistance vs. Junction Temperature



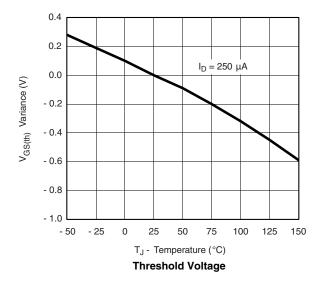
On-Resistance vs. Gate-to-Source Voltage

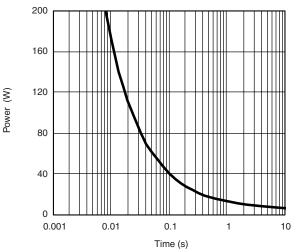
S - Source Current (A)

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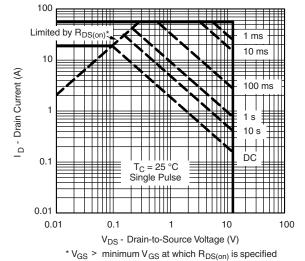
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# TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

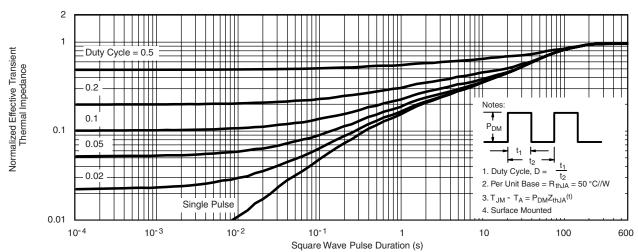




Single Pulse Power



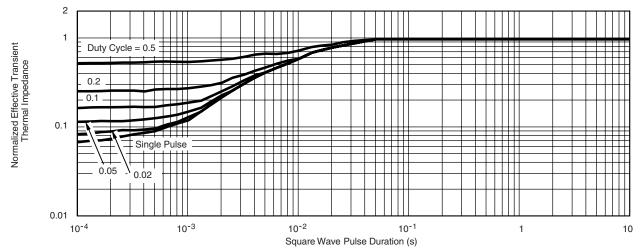
### Safe Operating Area Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="http://www.vishay.com/ppg?73164">http://www.vishay.com/ppg?73164</a>.

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